

# Chao Xiang

## List of Publications by Citations

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19  
papers

490  
citations

10  
h-index

22  
g-index

27  
ext. papers

941  
ext. citations

9.8  
avg, IF

4.17  
L-index

| #  | Paper   | IF   | Citations |
|----|---|------|-----------|
| 19 | Integrated turnkey soliton microcombs. <i>Nature</i> , <b>2020</b> , 582, 365-369   | 50.4 | 111       |
| 18 | Ultra-efficient frequency comb generation in AlGaAs-on-insulator microresonators. <i>Nature Communications</i> , <b>2020</b> , 11, 1331   | 17.4 | 77        |
| 17 | Narrow-linewidth III-V/Si/Si <sub>3</sub> N <sub>4</sub> laser using multilayer heterogeneous integration. <i>Optica</i> , <b>2020</b> , 7, 20  | 8.6  | 64        |
| 16 | Perspective on the future of silicon photonics and electronics. <i>Applied Physics Letters</i> , <b>2021</b> , 118, 220501  | 3.4  | 51        |
| 15 | Laser soliton microcombs heterogeneously integrated on silicon. <i>Science</i> , <b>2021</b> , 373, 99-103  | 33.3 | 37        |
| 14 | Ultra-narrow linewidth laser based on a semiconductor gain chip and extended SiN Bragg grating. <i>Optics Letters</i> , <b>2019</b> , 44, 3825-3828                                   | 3    | 35        |
| 13 | . <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , <b>2018</b> , 24, 1-9   | 3.8  | 32        |
| 12 | Effects of nonlinear loss in high-Q Si ring resonators for narrow-linewidth III-V/Si heterogeneously integrated tunable lasers. <i>Optics Express</i> , <b>2020</b> , 28, 19926-19936 | 3.3  | 15        |
| 11 | High-performance lasers for fully integrated silicon nitride photonics. <i>Nature Communications</i> , <b>2021</b> , 12, 6650   | 17.4 | 11        |
| 10 | High-Performance Silicon Photonics Using Heterogeneous Integration. <i>IEEE Journal of Selected Topics in Quantum Electronics</i> , <b>2022</b> , 28, 1-15                            | 3.8  | 10        |
| 9  | Ultra-precise optical-frequency stabilization with heterogeneous III-V/Si lasers. <i>Optics Letters</i> , <b>2020</b> , 45, 5275-5278   | 3    | 8         |
| 8  | High Speed Evanescent Quantum-Dot Lasers on Si. <i>Laser and Photonics Reviews</i> , <b>2021</b> , 15, 2100057  | 8.3  | 8         |
| 7  | Integrated chip-scale Si <sub>3</sub> N <sub>4</sub> wavemeter with narrow free spectral range and high stability. <i>Optics Letters</i> , <b>2016</b> , 41, 3309-12                  | 3    | 6         |
| 6  | Hybrid InP and SiN integration of an octave-spanning frequency comb. <i>APL Photonics</i> , <b>2021</b> , 6, 026102   | 5.2  | 6         |
| 5  | Silicon nitride chirped spiral Bragg grating with large group delay. <i>APL Photonics</i> , <b>2020</b> , 5, 101302   | 5.2  | 5         |
| 4  | Silicon-integrated nonlinear III-V photonics. <i>Photonics Research</i> , <b>2022</b> , 10, 535   | 6    | 3         |
| 3  | . <i>Journal of Lightwave Technology</i> , <b>2021</b> , 1-1  | 4    | 3         |

2 1550 nm laser with 320 Hz Lorentzian linewidth based on semiconductor gain chip and extended Si<sub>3</sub>N<sub>4</sub> Bragg grating **2019**, 2

1 (Invited) Temperature Stable III-V/Si/Si<sub>3</sub>N<sub>4</sub> Heterogeneous Integrated Laser. *ECS Meeting Abstracts*, **2020**, MA2020-02, 1832-1832 ○